

#### **Features**

Single-supply operation: 2.7 V to 5.5 V

High output current: ±250 mA

Low supply current: 750 μA/amplifier

Wide bandwidth: 3 MHz

Slew rate: 5 V/μs

No phase reversal

Low input currents

Unity gain stable

• Rail-to-rail input and output

#### **Application**

- Multimedia audio
- LCD drivers
- ASIC input or output amplifiers
- Headphone drivers

### **Description**

The CBM8531, CBM8532, and CBM8534 are single, dual, and quad rail-to-rail input/output single-supply amplifiers featuring 250mA output drive current. This high output current makes these amplifiers excellent for driving either resistive or capacitive loads. AC performance is very good with 3 MHz bandwidth,5 V/µs slew rate, and low distortion. All are guaranteed to operate from a 2.7 V single supply as well as a 5.5 V supply.

The very low input bias currents enable the CBM8531, CBM8532, and CBM8534 to be used for integrators, diode amplification, and other applications requiring low input bias current. Supply current is only 750  $\mu$ A per amplifier at 5 V, allowing low current applications to control high current loads.

The ability to swing rail-to-rail at the inputs and outputs enables designers to buffer CMOS DACs, ASICs, or other wide output swing devices in single-supply systems.

The CBM8531/CBM8532/CBM8534 are specified over the extended industrial temperature range (-40°C to +125°C). The CBM8531 is available in 8-lead SOIC, 5-lead SC70, and 5-lead SOT-23 packages. The CBM8532 is available in 8-lead SOIC, 8-lead MSOP, and 8-lead TSSOP surface-mount packages. The CBM8534 is available in narrow 14-lead SOIC and 14-lead TSSOP surface-mount packages.



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# **Revision Log**

Version	Revision date	Change content	Reason for Change	Modified by	Reviewed By	Note
V1.0	2025.5.13	Error update of the product's parameters	Error update	WW	LYL	



## **Pin Configurations**

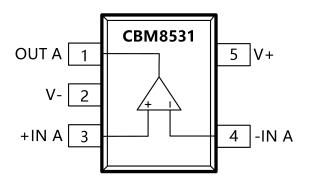


Figure 1. 5-Lead SC70 and 5-Lead SOT-23 (KS and RJ Suffixes)

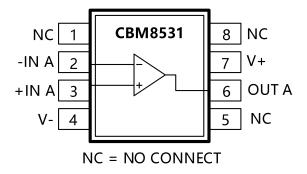


Figure 2. 8-Lead SOP (R Suffix)

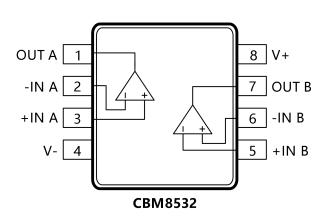


Figure 3. 8-Lead SOP8-Lead TSSOP-8 and 8-Lead MSOP (R, RU, and RM Suffixes)

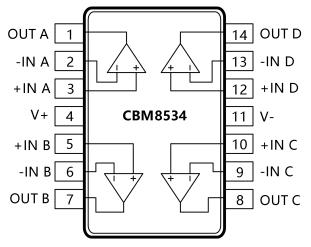


Figure 4. 14-Lead SOP and 14-Lead TSSOP (R and RU Suffixes)



# **Specifications-Electrical Characteristics**

 $V_S$ =3.0V,  $V_{CM}$ =1.35V,  $T_A$ =25°C, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS	'					
Office Malkage	N/				25	mV
Offset Voltage	V <sub>os</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			30	mV
Input Bias Current	I <sub>B</sub>			5	50	рА
input bias current	IB	-40°C ≤ T <sub>A</sub> ≤ +125°C			60	рА
Input Offset Current				1	25	рА
input Onset Current	I <sub>OS</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			30	pA
Input Voltage Range			0		3	V
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> =0V to 2.7V	38	45		dB
Large Signal Voltage Gain	A <sub>VO</sub>	$R_L = 2k\Omega$ , $V_O = 0.5V$ to 2.2V		25		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta_T$			20		μV/°C
Bias Current Drift	$\Delta_{\text{IB}}/\Delta_{\text{T}}$			50		fA/°C
Offset Current Drift	$\Delta_{\text{IOS}}/\Delta_{\text{T}}$			20		fA/°C
OUTPUT CHARACTERISTICS						
Outnut Valtaga High	V	I <sub>L</sub> = 10mA	2.85	2.92		V
Output Voltage High	V <sub>OH</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C	2.8			V
Output Voltage Low	V	I <sub>L</sub> = 10mA		60	100	mV
Output Voltage Low	V <sub>OL</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			125	mV
Output Current	I <sub>OUT</sub>			±250		mA
Closed-Loop Output Impedance	Z <sub>out</sub>	f = 1MHz, A <sub>V</sub> = 1		60		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V <sub>S</sub> = 2.7 V to 5.5 V	45	55		dB
Supply Current/Amalifica		V <sub>O</sub> = 0 V		0.70	1	mA
Supply Current/Amplifier	I <sub>SY</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			2.5	mA
DYNA PEMIC RFORMANCE						
Slew Rate	SR	$R_L = 2 k\Omega$		3.5		V/µs
Settling Time	Ts	To 0.01%		1.6		μs
Gain Bandwidth Product	GBP			2.2		MHz



Phase Margin	фо			70		Degrees	
Channel Separation	CS	$f = 1kHz, R_L = 2k\Omega$		65		dB	
NOISE PERFORMANCE							
Voltage Noise Density		f = 1kHz		45		nV/√ <i>Hz</i>	
	en	f = 10kHz		30		nV/√ <i>Hz</i>	
Current Noise Density	İn	f = 1kHz		0.05		$pA/\sqrt{Hz}$	

### $V_S$ = 5.0V, $V_{CM}$ = 2.5V, $T_A$ = 25°C, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit		
INPUT CHARACTERISTICS								
Office t Welling	.,,				25	mV		
Offset Voltage	V <sub>os</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			30	mV		
land Ria Coment				5	50	рА		
Input Bias Current	I <sub>B</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			60	рА		
Input Offset Current				1	25	рА		
Input Offset Current	I <sub>OS</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			30	рА		
Input Voltage Range			0		5	V		
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = 0V to 5V	38	47		dB		
Large Signal Voltage Gain	A <sub>VO</sub>	$R_L = 2k\Omega$ , $V_O = 0.5V$ to 4.5V	15	80		V/mV		
Offset Voltage Drift	$\Delta V_{OS}/\Delta_T$	-40°C ≤ T <sub>A</sub> ≤ +125°C		20		μV/°C		
Bias Current Drift	$\Delta_{\text{IB}}/\Delta_{\text{T}}$			50		fA/°C		
Offset Current Drift	$\Delta_{IOS}/\Delta_{T}$			20		fA/°C		
OUTPUT CHARACTERISTICS								
Output Voltage High	V	I <sub>L</sub> = 10mA	4.9	4.94		V		
Output Voltage High	V <sub>OH</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C	4.85			V		
Outrout Valtagral and	W	I <sub>L</sub> = 10mA		50	100	mV		
Output Voltage Low	V <sub>OL</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			125	mV		
Output Current	I <sub>OUT</sub>			±250		mA		
Closed-Loop Output Impedance	Z <sub>OUT</sub>	f = 1MHz, A <sub>V</sub> = 1		40		Ω		
POWER SUPPLY								
Power Supply Rejection Ratio	PSRR	V <sub>S</sub> = 2.7V to 5.5V	45	55		dB		
Cont. Const. (Ann. 177)		V <sub>O</sub> = 0V		0.75	1.25	mA		
Supply Current/Amplifier	I <sub>SY</sub>	-40°C ≤ T <sub>A</sub> ≤ +125°C			1.75	mA		





DYNA PEMIC RFORMANCE							
Slew Rate	SR	$R_L = 2 k\Omega$		5		V/µs	
Full-Power Bandwidth	BW <sub>P</sub>	1% distortion		350		KHz	
Settling Time	ts	To 0.01%		1.4		μs	
Gain Bandwidth Product	GBP			3		MHz	
Phase Margin	фо			70		Degrees	
Channel Separation	CS	f = 1 kHz, RL = 2 kΩ		65		dB	
NOISE PERFORMANCE							
Valta an Naire Densita		f = 1 kHz		45		nV/√ <i>Hz</i>	
Voltage Noise Density	<b>e</b> n	f = 10 kHz		30		nV/√ <i>Hz</i>	
Current Noise Density	İn	f = 1 kHz		0.05		pA/√ <i>Hz</i>	



## **Absolute Maximum Ratings**

Parameter	Rating	Parameter	Rating
Supply Voltage (VS)	7V	Operating Temperature Range	−40°C to +125°C
Input Voltage	GND to V <sub>s</sub>	Junction Temperature Range	-65℃ to +150℃
Differential Input Voltage	±6 V	Lead Temperature (Soldering,60 sec)	300℃
Storage Temperature Range	-65°C to +150°C		

# **Typical Performance Characteristics**

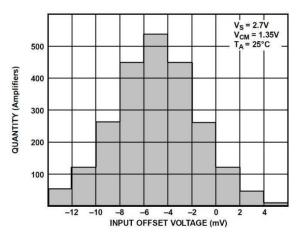


Figure 5. Input Offset Voltage Distribution

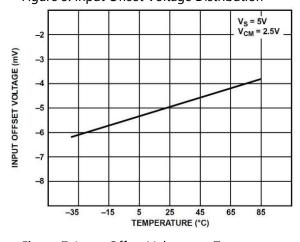


Figure 7. Input Offset Voltage vs. Temperature

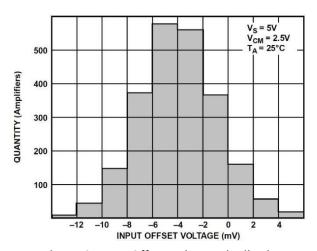


Figure 6. Input Offset Voltage Distribution

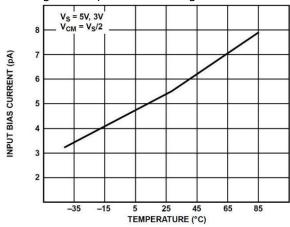
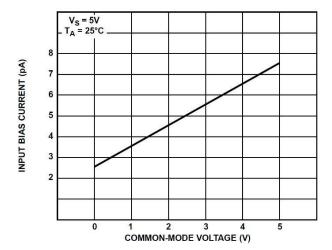


Figure 8. Input Bias Current vs. Temperature





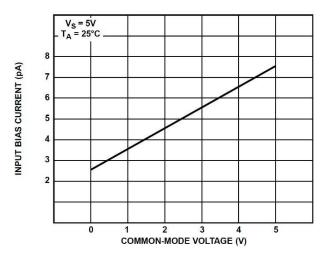
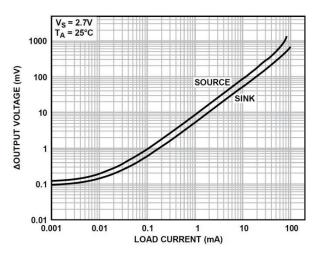


Figure 9. Input Bias Current vs.

Figure 10. Input Offset Current vs. Temperature

#### Common-Mode Voltage



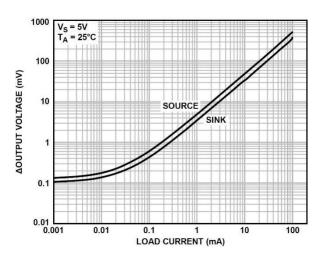
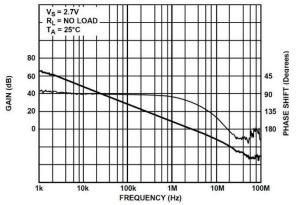
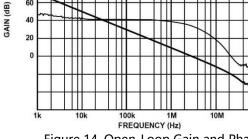


Figure 11. Output Voltage to Supply Rail vs.
Load Current

Figure 12. Output Voltage to Supply Rail vs. Load Current





V<sub>S</sub> = 5V R<sub>L</sub> = NO LOAD T<sub>A</sub> = 25°C

Figure 13. Open-Loop Gain and Phase Shift vs. Frequency

Figure 14. Open-Loop Gain and Phase Shift vs. Figure Frequency

PHASE SHIFT (Degrees



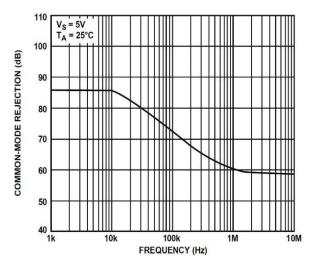


Figure 15. Common-Mode Rejection vs. Frequency

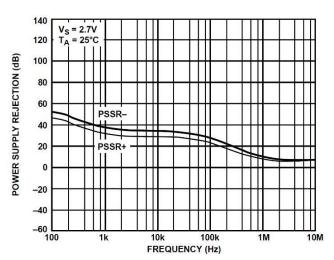


Figure 16. Power Supply Rejection vs. Frequency

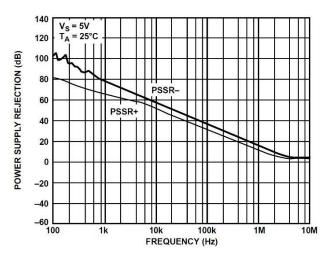


Figure 17. Power Supply Rejection vs. Frequency

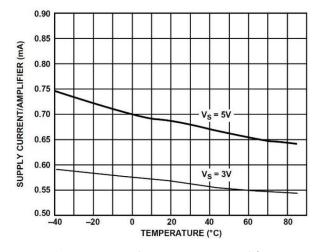


Figure 18. Supply Current per Amplifier vs. Figure Temperature

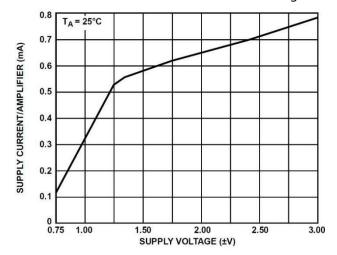


Figure 19. Supply Current per Amplifier vs. Supply Voltage



## **Theory Of Operation**

The CBM8531/CBM8532/CBM8534 are all CMOS, high output current drive, rail-to-rail input/output operational amplifiers. Their high output current drive and stability with heavy capacitive loads make the CBM8531/CBM8532/CBM8534 excellent choices as drive amplifiers for LCD panels.

Figure 20 illustrates a simplified equivalent circuit for the CBM8531/CBM8532/CBM8534. Like many rail-to-rail input amplifier configurations, it comprises two differential pairs, one N-channel (M1 to M2) and one P-channel (M3 to M4). These differential pairs are biased by 50 μA current sources, each with a compliance limit of approximately 0.5 V from either supply voltage rail. The differential input voltage is then converted into a pair of differential output currents. These differential output currents are then combined in a compound folded-cascade second gain stage (M5 to M9). The outputs of the second gain stage at M8 and M9 provide the gate voltage drive to the rail-to-rail output stage. Additional signal current recombination for the output stage is achieved using M11 to M14.

To achieve rail-to-rail output swings, the CBM8531/CBM8532/ CBM8534 design employs a complementary, common source output stage (M15 to M16). However, the output voltage swing is directly dependent on the load current because the difference between the output voltage and the supply is determined by the CBM8531/CBM8532/CBM8534′s output transistors on channel resistance. The output stage also exhibits voltage gain by virtue of the use of common source amplifiers; as a result, the voltage gain of the output stage (thus, the open-loop gain of the device) exhibits a strong dependence on the total load resistance at the output of the CBM8531/CBM8532/CBM8534.



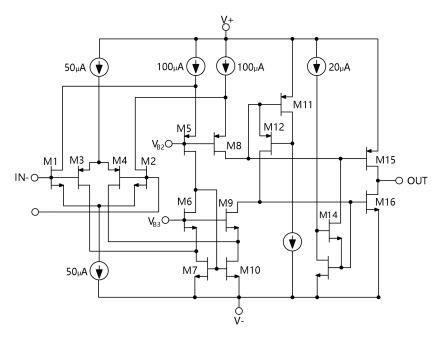


Figure 20. Simplified Equivalent Circuit

#### **Short-Circuit Protection**

As a result of the design of the output stage for the maximum load current capability, the CBM8531/CBM8532/CBM8534 do not have any internal short-circuit protection circuitry. Direct connection of the output of the CBM8531/CBM8532/CBM8534 to the positive supply in single-supply applications destroys the device. In applications where some protection is needed, but not at the expense of reduced output voltage headroom, a low value resistor in series with the output, as shown in Figure 21, can be used. The resistor, connected within the feedback loop of the amplifier, has very little effect on the performance of the amplifier other than limiting the maximum available output voltage swing. For single 5 V supply applications, resistors less than  $20~\Omega$  are not recommended.

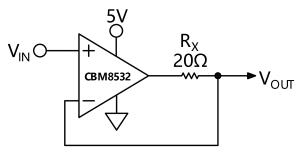


Figure 21. Output Short-Circuit Protection



#### **Power Dissipation**

Although the CBM8531/CBM8532/CBM8534 are capable of providing load currents to 250 mA, the usable output load current drive capability is limited to the maximum power dissipation allowed by the device package used. In any application, the absolute maximum junction temperature for the CBM8531/CBM8532/CBM8534 is 150°C. The maximum junction temperature should never be exceeded because the device could suffer premature failure. Accurately measuring power dissipation of an integrated circuit is not always a straightforward exercise; therefore, Figure 22 is provided as a design aid for either setting a safe output current drive level or selecting a heat sink for the package options available on the CBM8531/CBM8532/CBM8534.

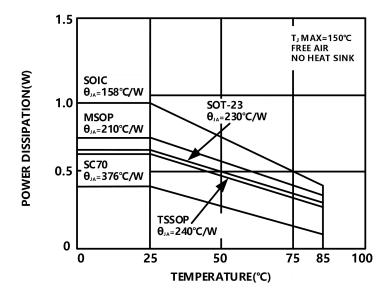


Figure 22. Maximum Power Dissipation vs. Ambient Temperature T<sub>J</sub>



### **Applications Information**

#### HIGH OUTPUT CURRENT, BUFFERED REFERENCE/REGULATOR

Many applications require stable voltage outputs relatively close in potential to an unregulated input source. This low dropout type of reference/regulator is readily implemented with a rail-to-rail output op amp and is particularly useful when using a higher current device, such as the CBM8531/CBM8532/CBM8534. A typical example is the 3.3V or 4.5V reference voltage developed from a 5V system source. Generating these voltages requires a three terminal reference, such as the REF196 (3.3V) or the REF194 (4.5V), both of which feature low power, with sourcing outputs of 30 mA or less. Figure 23 shows how such a reference can be outfitted with an CBM8531/CBM8532/CBM8534 buffer for higher currents and/or voltage levels, plus sink and source load capability.

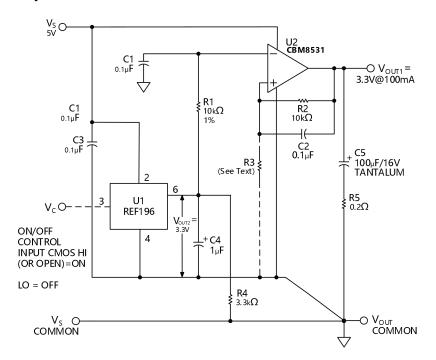


Figure 23. High Output Current Reference/Regulator

The low dropout performance of this circuit is provided by stage U2, an CBM8531 connected as a follower/buffer for the basic reference voltage produced by U1. The low voltage saturation characteristic of the CBM8531/CBM8532/CBM8534 allows up to 100mA of load current in the illustrated use, as a 5V to 3.3V converter with good dc accuracy. In fact, the dc output voltage change for a 100mA load current delta measures less than 1mV. This corresponds to an equivalent output impedance of < 0.01  $\Omega$ . In this application, the stable 3.3 V from U1 is applied



to U2 through a noise filter, R1 to C1. U2 replicates the U1 voltage within a few millivolts, but at a higher current output at  $V_{OUT1}$ , with the ability to both sink and source output current(s), unlike most IC references. R2 and C2 in the feedback path of U2 provide additional noise filtering.

Transient performance of the reference/regulator for a 100mA step change in load current is also quite good and is largely determined by the R5 to C5 output network. With values as shown, the transient is about 20mV peak and settles to within 2mV in less than 10µs for either polarity. Although room exists for optimizing the transient response, any changes to the R5 to C5 network should be verified by experiment to preclude the possibility of excessive ringing with some capacitor types.

To scale  $V_{OUT2}$  to another (higher) output level, the optional resistor R3 (shown dotted in Figure 23) is added, causing the new  $V_{OUT1}$  to become

$$V_{OUT1} = V_{OUT2} \times (1 + \frac{R2}{Rt})$$

The circuit can either be used as shown, as a 5 V to 3.3 V reference/regulator, or with on/off control. By driving Pin 3 of U1 with a logic control signal as noted, the output is switched on/off. Note that when on/off control is used, R4 must be used with U1 to speed on/off switching.

#### SINGLE-SUPPLY HEADPHONE AMPLIFIER

Because of its speed and large output drive, the CBM8531/ CBM8532/CBM8534 make an excellent headphone driver, as illustrated in Figure 24. Its low supply operation and rail-to-rail inputs and outputs give a maximum signal swing on a single 5V supply. To ensure maximum signal swing available to drive the headphone, the amplifier inputs are biased to V+/2, which in this case is 2.5V. The  $100k\Omega$  resistor to the positive supply is equally split into two  $50k\Omega$  resistors, with their common point bypassed by  $10\mu F$  to prevent power supply noise from contaminating the audio signal.

The audio signal is then ac-coupled to each input through a  $10\mu F$  capacitor. A large value is needed to ensure that the 20 Hz audio information is not blocked. If the input already has the proper dc bias, the ac coupling and biasing resistors are not required. A  $270\mu F$  capacitor is used at the output to couple the amplifier to the headphone. This value is much larger than that used for the input because of the low impedance of the head-phones, which can range from  $32\Omega$  to  $600\Omega$ . An additional  $16\Omega$  resistor is used in series with the output capacitor to protect the output stage of the op amp by limiting the capacitor discharge current. When driving a  $48\Omega$  load, the circuit exhibits less than 0.3% THD+N at output drive levels of 4Vp-p.



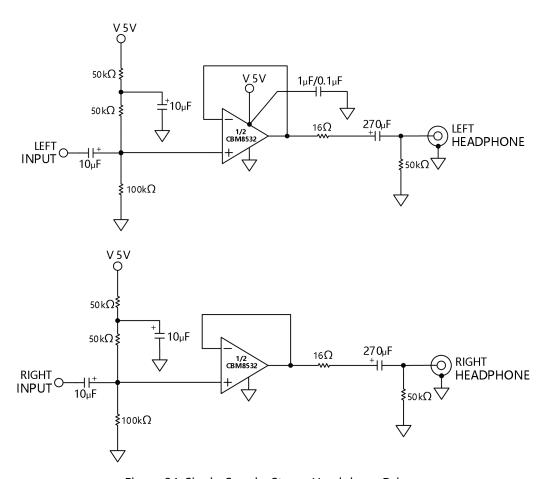


Figure 24. Single-Supply, Stereo Headphone Driver



# **Package Outline Dimensions**

### **SC70-5**

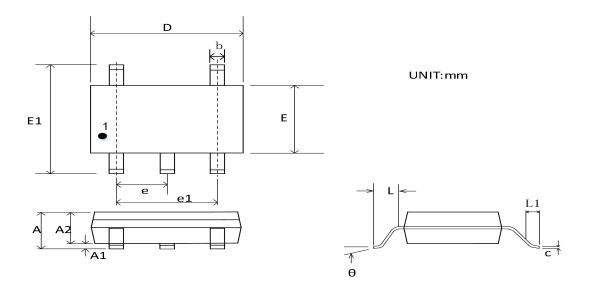


Figure 25. SC70-5 Outline Package

Cumbal	Dimensions I	n Millimeters	Dimensions Inches		
Symbol	Min	Max	Min	Max	
Α	0.800	1.100	0.031	0.043	
<b>A1</b>	0.000	0.100	0.000	0.004	
A2	0.700	1.000	0.028	0.039	
b	0.150	0.300	0.006	0.012	
С	0.080	0.220	0.003	0.009	
D	1.800	2.200	0.071	0.087	
E	1.150	1.350	0.045	0.053	
<b>E</b> 1	1.800	2.400	0.071	0.094	
е	0.650	BSC	0.026 BSC		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.02	21 REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	



## SOT23-5

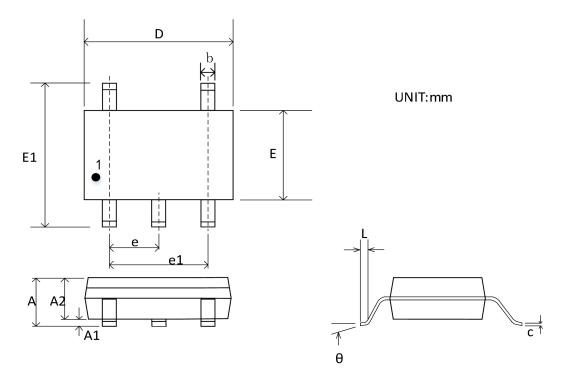


Figure 26. SOT23-5 Outline Package

Complete al	Dimensions I	n Millimeters	Dimensions Inches		
Symbol	Min	Max	Min	Max	
Α		1.450		0.057	
<b>A</b> 1		0.150		0.006	
A2	0.900	1.300	0.035	0.051	
b	0.300	0.500	0.012	0.020	
С	0.080	0.220	0.003	0.009	
D	2.900	) BSC	0.114 BSC		
E	1.600	) BSC	0.063 BSC		
E1	2.80	BSC	0.110 BSC		
e	0.950	) BSC	0.037 BSC		
e1	1.900 BSC		0.075 BSC		
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



## SOP-8

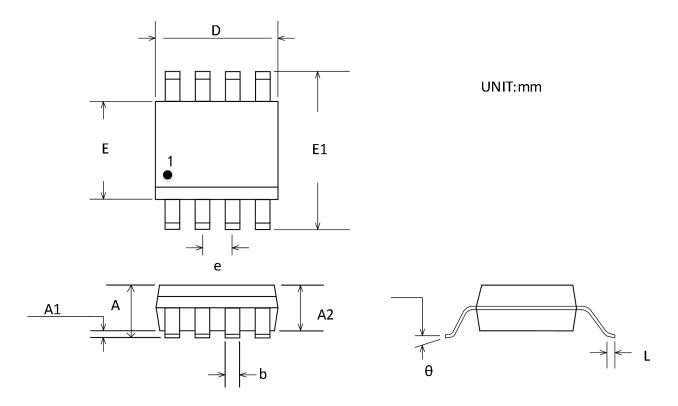


Figure 27. SOP-8 Outline Package

Cumbal	Dimensions I	n Millimeters	Dimensions Inches		
Symbol	Min	Max	Min	Max	
Α	1.350	1.750	0.053	0.069	
<b>A</b> 1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.310	0.510	0.012	0.020	
D	4.800	5.000	0.189	0.197	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.270 BSC		0.050 BSC		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



## MSOP-8

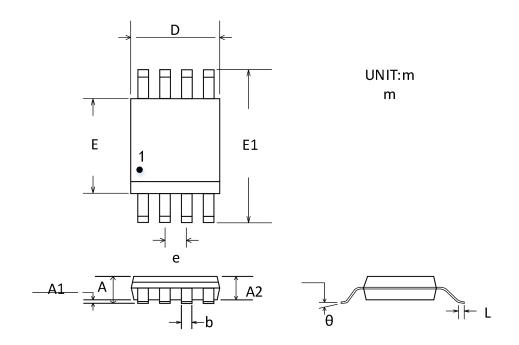


Figure 28. MSOP-8 Outline Package

Sumb al	Dimensions I	n Millimeters	Dimensions Inches		
Symbol	Min	Max	Min	Max	
Α	0.820	1.100	0.032	0.043	
<b>A</b> 1	0.000	0.150	0.000	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.220	0.380	0.009	0.015	
D	2.800	3.200	0.110	0.126	
E	2.800	3.200	0.110	0.126	
E1	4.650	5.150	0.183	0.203	
е	0.650	) BSC	0.026 BSC		
L	0.400	0.800	0.016	0.031	
θ	0°	8°	0°	8°	



## TSSOP-8

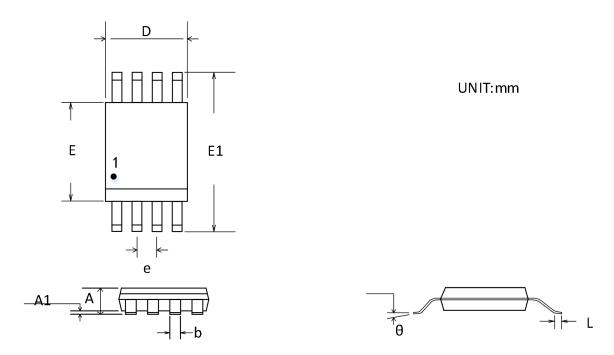


Figure 29. TSSOP-8 Outline Package

Symple al	Dimensions I	n Millimeters	Dimensions Inches		
Symbol	Min	Max	Min	Max	
Α		1.20		0.047	
<b>A</b> 1	0.05	0.15	0.002	0.006	
b	0.19	0.30	0.007	0.012	
D	2.90	3.10	0.114	0.122	
E	4.30	4.50	0.169	0.171	
E1	6.40	BSC	0.252BSC		
е	0.65 BSC		0.026 BSC		
L	0.45	0.75	0.018	0.030	
θ	0°	8°	0°	6°	

## TSSOP-14

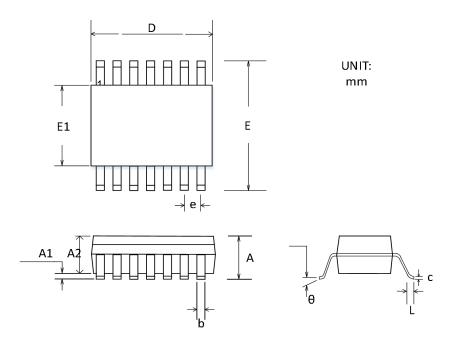


Figure 30. TSSOP-14 Outline Package

Symbol	Dimensions In Millimeters		Dimensions Inches	
	Min	Max	Min	Мах
Α		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
С	0.090	0.200	0.004	0.008
D	4.900	5.100	0.193	0.201
E	6.40 BSC		0.252 BSC	
E1	4.300	4.500	0.169	0.177
е	0.650 BSC		0.026 BSC	
L	0.450	0.750	0.018	0.030
θ	0°	8°	0°	8°

## SOP-14

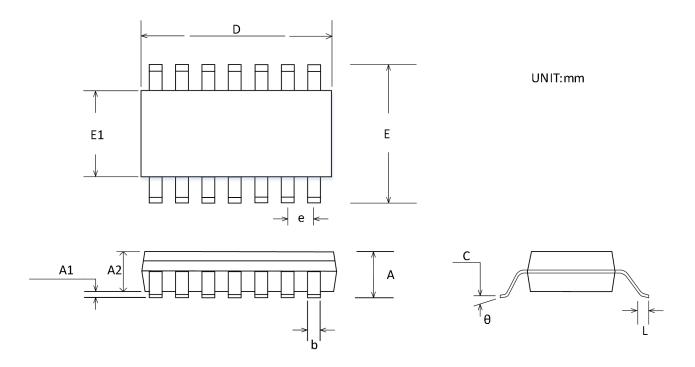


Figure 31. SOP-14 Outline Package

Symbol	Dimensions In Millimeters		Dimensions Inches	
	Min	Max	Min	Max
Α	1.350	1.750	0.053	0.069
<b>A</b> 1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.310	0.510	0.012	0.020
С	0.170	0.250	0.070	0.010
D	8.550	8.750	0.337	0.345
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.158
е	1.270 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



# **Package/Ordering Information**

ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE	PACKAGE MARKING	TRANSPOT MEDIA,QUANTILY
CBM8531ASC7	-40°C~125°C	SC70-5	8531	Tape and Reel,3000
CBM8531AST5	-40°C~125°C	SOT23-5	8531	Tape and Reel,3000
CBM8531AS8	-40°C~125°C	SOP-8	CBM8531A	Tape and Reel,2500
CBM8531AS8-RL	-40°C~125°C	SOP-8	CBM8531A	Tape and Reel,3000
CBM8531AS8-REEL	-40°C~125°C	SOP-8	CBM8531A	Tape and Reel,4000
CBM8532AS8	-40°C~125°C	SOP-8	CBM8532A	Tape and Reel,2500
CBM8532AS8-RL	-40°C~125°C	SOP-8	CBM8532A	Tape and Reel,3000
CBM8532AS8-REEL	-40°C~125°C	SOP-8	CBM8532A	Tape and Reel,4000
CBM8532AMS8	-40°C~125°C	MSOP-8	A32	Tape and Reel,3000
CBM8532ATS8	-40°C~125°C	TSSOP-8	32T	Tape and Reel,2500
CBM8532ATS8-RL	-40°C~125°C	TSSOP-8	32T	Tape and Reel,3000
CBM8532ATS8-REEL	-40°C~125°C	TSSOP-8	32T	Tape and Reel,4000
CBM8534AS14	-40°C~125°C	SOP-14	CBM8534AS	Tape and Reel,2500
CBM8534AS14-RL	-40°C~125°C	SOP-14	CBM8534AS	Tape and Reel,3000
CBM8534AS14-REEL	-40°C~125°C	SOP-14	CBM8534AS	Tape and Reel,4000
CBM8534ATS14	-40°C~125°C	TSSOP-14	CBM8534AT	Tape and Reel,2500
CBM8534ATS14-RL	-40°C~125°C	TSSOP-14	CBM8534AT	Tape and Reel,3000
CBM8534ATS14-REEL	-40°C~125°C	TSSOP-14	CBM8534AT	Tape and Reel,4000